

International Journal of Scientific Research in Physics and Applied Sciences Vol.7, Issue.3, pp.1-5, June (2019) DOI: https://doi.org/10.26438/ijsrpas/v7i3.15

E-ISSN: 2348-3423

Static Pair Correlation Functions and Static Structure Factors of Unidirectional Quantum Systems

G. Dhingra^{1*}

Department of Physics, Maharshi Dayanand University, Rohtak-124001, India

*Corresponding Author: grimadhingra@gmail.com, Tel: +91-7404220854

Available online at: www.isroset.org

Received: 22/May/2019, Accepted: 12/Jun/2019, Online: 30/Jun/2019

Abstract— Two of the structural functions, static pair correlation function of electrons around positively charged particles and static structure factor, have been theoretically calculated for a one dimensional quantum system with two mobile components occupying same charge density at equal temperatures. The structural functions have been investigated for their density and mass dependence. The reported values of static pair correlation function and structure factors are found to be dependent upon linear density and mass of positive components. Static pair correlation functions for a wide range of temperature, $100K \le T \le 1500K$, has also been generated theoretically. A variation, though diminutive, with temperature has been observed.

Keywords— Static pair correlation function, Static structure factor, Complex dielectric functions, Plasma frequency, Fabrication techniques

I. INTRODUCTION

Distinguished quantum systems; quantum dots, quantum wires, quantum wells are dimensionally confined systems whose structural and kinetic properties are quantized in terms of their charge carriers. Such systems, particularly, those restricted to a single dimension were previously supposed not to be ideally realizable. With the advent of advance fabrication techniques[1-9], however, it has become possible to develop such systems in laboratory. Electron beam lithography and wet chemical etching [9,10]are examples of such techniques, used to synthesize CdZnSe/ZnSe or InGaAs/GaAs hetero structures based one and two dimensional quantum systems.

In the present communication, two structural functions, static pair correlation function and static structure factor, of such a one dimensional quantum system has been investigated for their variation and dependence upon various physical parameters, like, temperature, mass and number density of its constituent particles. The mono-dimensional system has been assumed to be a two component system, positive and negative charge carriers, such that they constitute an overall neutral assembly of charged particles. The quantum behaviour of a one dimensional system can be specified by $2r_s < \lambda_{th}$. Here, λ_{th} is the condition de-broglie wavelength(= $h/\sqrt{2mk_BT}$; h, m, k_B & T are planck's constant, mass of charge carrier, boltzman constant & temperature respectively) and $2r_s$ represents the inter-particle separation.

This paper has been organized into four different sections: Introduction, Mathematical formalism, Results and discussion and Conclusion. In Section I a brief review of literature related to current research problem has been made. Section II, mathematical expression for distinct physical quantities has been provided. In section III, detailed computational results as obtained for quantum assembly under consideration has been provided and been thoroughly discussed. Section IV yields the conclusions drawn from the computational results.

II. MATHEMATICAL FORMALISM

Paired correlations of pair of electron and positively charged particles at time, t=0, in any system of moving particles can be expressed through its static pair correlation function, g(r). Expression for g(r) function [11-13] for a one dimensional quantum system can be given as follows:

$$g(r) = 1 + \frac{1}{2\pi} \int_{-\infty}^{\infty} \left[-\frac{z}{n} \operatorname{Re}\left(\frac{1}{\varepsilon_{\pm}(\kappa, \hbar\kappa^{2}/2M)} - 1\right) + \frac{z}{n} \int_{0}^{\infty} d\omega \operatorname{Im}\left(\frac{1}{\varepsilon_{\pm}(\kappa, \omega)}\right) \times P\left(\frac{\hbar\kappa^{2}/2M}{\omega^{2} - (\hbar\kappa^{2}/2M)}\right) \right] e^{i\omega} d\kappa$$

(1)

In expression (1), M is mass of positively charged particle, z is unit positive integer, $\mathcal{E}(\kappa, \omega)$ is its complex dielectric function and $\kappa \& \omega$ are wave-vector & frequencies of quantum system respectively [14-17].

The static structure factor represents the coupled motion of electrons around positively charged impurity in Fourierspace. Expression for static structure factor is given as follows:

$$S(\kappa) = f_{-}\left(1 + \frac{\kappa_{+}^{2}f_{+}}{\kappa^{2}}\right) / \left(1 + \frac{\kappa_{+}^{2}f_{+}}{\kappa^{2}} + \frac{\kappa_{-}^{2}f_{-}}{\kappa^{2}}\right)$$
(2)

Here, $\kappa_{+}^{2} = \kappa_{-}^{2} = \frac{\omega_{p\pm}}{v_{+}^{2}}$

And,

$$f_{\pm} = e^{-h^{2}\kappa^{2}/8m_{\pm}^{2}v_{\pm}^{2}} \left\{ 1 + \frac{1}{3} \left(\frac{h\kappa}{2\sqrt{2} m_{\pm}v_{\pm}} \right)^{2} + \frac{1}{10} \left(\frac{h\kappa}{2\sqrt{2} m_{\pm}v_{\pm}} \right)^{4} + \dots \right\}$$
(4)

(3)

In expression (3), $v_{\pm} = \sqrt{k_B T_{\pm} / m_{\pm}}$, are thermal velocities of positive and negative components and $\omega_{p\pm} = \sqrt{\pi n_{\pm} e^2 \kappa^2 (\ln \kappa) / m_{\pm}}$, are plasma frequencies [18-21] of positively and negatively charged mobile particles.

III. RESULTS AND DISCUSSION

Static pair correlation function of a weakly bound one dimensional quantum system is given by the expression (1). The system is constituted by neutral assembly of negatively (electrons) and positively charged particles having some finite mass. The same expression is used to calculate the static pair correlation function, g(r), of a one dimensional quantum system having number density of 0.95x10⁻² particles per Å. Such a dense system correspond to, $2r_s = 1.05263 \times 10^{-5}$ 6 cm, where, $2r_{s}$ indicates the mean inter-particle distance. One can notice that to retain charge neutrality, number of positively charged particles are assumed to be equal to number of negatively charged particles. Further, the system is considered to be at a temperature, T=100K. Thermal de-Broglie wavelength, λ_{th} , of the plasma system under investigation turns to be $\lambda_{th} = 131.7$ Å and therefore, $2r_s < \lambda_{th}$, which indicates the system is mildly quantum mechanical wherein the particles are weakly coupled.

Computed results for g(r) function of such a quantum mechanical assembly of paired particles are plotted in Figure 1, as their variation with r/r_s, for different masses of positively charged particles(i.e. $m_{+} = 1.0m_{e}(-)$, $2.5m_{e}(-)$, $5.0m_{e}(-)$, $7.5m_{e}(-)$ and $10.0m_{e}(-)$).



Figure 1: Variation of static pair correlation function with r/r_s for different masses of positively charged particles: $1.0m_e(-)$, $2.5m_e(-)$, $5.0m_e(-)$, $7.5m_e(-)$ and $10.0m_e(-)$

As is evident from the figure, g(r) function shows the characteristic trend of variation with r/r_s , g(r=0) is maximum and decreases to a minimum for lower values of r. With further increase in r/r_s, it increases and thereafter fluctuates about g(r)=1. However, with increase in mass of positive charge, the maximum value of g(r) i.e. g(r=0) increases, is numerically lowest for $m_{+} = m_{e}$ and is the highest for m_{+} =10.0 m_e . Also the decrease with increase in r/r_s is, sharper for heavier positive charge particles as compared to lighter positive charge particles and is least when mass of positively charged particle is equal to negatively charged particle i.e. mass of electron. This comparative trend is same for further increase in r/r_s , as can be seen from the figure, the height of secondary maxima is most sharp for $m_{+} = 10.0 m_{e}$ and is least sharp for $m_{+} = m_{e}$. This can also be noted from the figure 1(a), that the secondary and thereafter maxima are shifted towards higher values of r/r_s with decrease in mass, for m_+ =1.0 m_e the secondary maxima value is at r/r_s~0.31, whereas for $m_+ = 10.0 \ m_e$ this lies at r/r_s~2.3. The overall trend, however, remains the same for all values of masses of positive component, characterizing the short range order of the system. In Figure 1(b) and Figure 1(c), same variation is

shown up to $r/r_s = 1.0$ and $r/r_s = 0.6$ As compared to classical system with similar number densities[13], the oscillations in g(r) about one in present system seems to be less damped.

In Figure2, variation of function of system of particles with same number density and r_s value is plotted for different temperatures ranging from100K \leq T \leq 1500K, mass of the positive component is assumed to be five times the mass of the negative component. Here also, the static pair correlation function retains its peculiar behaviour even at higher temperatures (i.e. T= 1000K &1500K). Variation at T=100K is shown with(—); T=500K(—); T=1000K(—); and T=1500K with(—).



Figure 2: Variation of static pair correlation function with r/r_s at different temperatures: (—) 100K,(—) 500K, (—) 1000K and (—) 1500K.

As is clearly indicated by the figure, there is no evident change in the variation in g(r) function at different temperatures and the plots at different temperatures are hardly distinguishable. For all temperature values, there is a sharp decrease in g(r) for $r/r_s \le 0.2$ and thereafter a periodic variation about 1.0, with constant decrease in amplitude, is seen with increase in r/r_s values. Moreover, for all values of temperature, g(r) function saturates to a numerical value of one for $r/r_s > 2.75$, as is shown in Figure 2(b). In Figure 2(c), the same variation is shown for $r/r_s < 0.1$. There is a little decrease in g(r=0) values with increase in temperature. This variation of g(r) function with increase in temperature is in contrast to that of one component [13] system which shows makeable difference in variation of g(r) function at different temperatures.

Variation of g(r) function with r/r_s for two component quantum system at T=100K is plotted in Figure3 at four different densities of electrons: n=0.56x10⁻² Å⁻¹ with (—); n=0.95x10⁻²Å⁻¹ (—); n=2.8x10⁻²Å⁻¹(—); n=5.6x10⁻²Å⁻¹ (—). The respective $2r_s$ values are $1.78x10^{-6}$ cm; $1.05x10^{-6}$ cm; $0.357x10^{-6}$ cm; $0.1786x10^{-6}$ cm. Hence, effect of density variation up to one order are being investigated.

As is clearly evident from the plot, with increase in density of particles, amplitude of g(r) at r=0, decreases remarkably. Also, the g(r) function for largest number of particles occupying a unit length, shows the least damping, at $n=0.56 \times 10^{-2} \text{\AA}^{-1}$ $g(r=0) \cong 10$ whereas at $n=5.6 \times 10^{-2} \text{\AA}^{-1}$ ¹, $g(r=0) \ge 1.9$. Moreover, quantum systems with greater interparticle separations show much sharper decrease in g(r)function value as compared to least denser systems for $2r_s=1.786 \times 10^{-6}$ cm & 1.056×10^{-6} cm, it decreases to minimum for $r/r_s < 0.15$ whereas for $2r_s = 0.356 \times 10^{-6}$ & 0.1786×10^{-6} cm, it attains the minimum for $r/r_s = 0.4 \& 0.7$ respectively. For larger values of r/r_s , trend of variation is same for all values of number density, the function shows oscillatory behaviour about one with decreasing amplitude and for further increase in r/r_s attains the constant value (i.e. one). Variation for larger values of r/r_s at all densities is shown in figure 3(b), and it can be observed from the figure that g(r) remains constant (=1.0) for $r/r_s \ge 2.5$, at all number densities.

Int. J. Sci. Res. in Physics and Applied Sciences



Figure 3: Variation of static pair correlation function with r/r_s for different number densities: $n=0.56x10^{-2} \text{ Å}^{-1}$ with (—); $n=0.95x10^{-2} \text{ Å}^{-1}$ (—); $n=2.8x10^{-2} \text{ Å}^{-1}$ (—); $n=5.6x10^{-2} \text{ Å}^{-1}$ (—).

Static structure factor expresses the correlated movement between pair of positive and negative charge particles in



Figure 4:Variation of static structure factor $S(\kappa)$ with wave-vector κ : 100K(—) and 500K(—).

Fourier space. Such a function has been computed by expression (2) and its variation versus wave-vector is shown in Figure4. Here, number density has been considered to be $0.95 \times 10^{-2} \ cm^{-1}$ which corresponds to $2r_s$ value $1.056 \times 10^{-6} \ cm$. It can be observed that structure factor, $S(\kappa)$ shows a proportional increase for increase in wave-vector. It can further be noticed that values for $S(\kappa)$ function increases with increase in temperature at 100 K(--) and 500 K(--). For lower values of wave-vector, κ ($\kappa \leq 5 \ cm^{-1}$), there is a little variation with increase in temperature. With further increase in κ values, however, the two plots become distinguishable and for $\kappa \geq 7.5 \ cm^{-1}$, the structure factor for system at higher temperature (500 K) is quite high in comparison to that at lower temperature (100 K).

IV. CONCLUSION

Static pair correlation function for one dimensional quantum system is found to be dependent upon number density of particles. The function shows a little variation with change in temperature but changes drastically for increase in mass of the positive component. Static structure factor is also found to be temperature dependant. The trend for variation is peculiar and remained unchanged for change in physical parameters.

The preferred spelling of the word "acknowledgment" in America is without an "e" after the "g". Avoid the stilted expression, "One of us (R. B. G.) thanks . . ." Instead, try "R. B. G. thanks". Put sponsor acknowledgments in the unnumbered footnote on the first page.

REFERENCES

- S. A. Hartstein, R.A.Webb, A.B. Fowler and J.J. Wainer, "Onedimensional conductance in silicon mosfet's", Surf Sci, Vol. 142, pp. 1-13, 1984.
- [2] W. Hansen, M. Horst, J.P. Kotthaus, U. Merkt, Ch. Sikorski and K. Ploog, "Intersubband resonance in quasi one-dimensional

Int. J. Sci. Res. in Physics and Applied Sciences

Vol.7(3), Jun 2019, E-ISSN: 2348-3423

inversion channels", Phys. Rev Lett, Vol.58(24), pp. 2586-2589, 1987.

- [3] J.H.F Scott-Thomas, S.B. Field, M.A. Kastner, H.I. Smith and D.A. Antoniaddis, "Conductance Oscillations Periodic in the Density of a One-Dimensional Electron Gas" Phys Rev Lett, Vol. 62(5), pp. 583-586, 1989.
- [4] Pepper M. and Uren M.J.," The Wigner glass and conductance oscillations in silicon inversion layers, J Phys C, Vol.15(20), pp L617-L626,1982.
- [5] T. Demel, D. Heitmann, P. Grambow and K. Ploog, "One-dimensional electronic systems in ultrafine mesa-etched single and multiple quantum well wires", Appl phys Lett, Vol. 53(22), pp. 2176-2178, 1988.
- [6] A.B. Fowler, A. Hartstein and R.A. Webb, "Conductance in Restricted-Dimensionality Accumulation Layers", Phys Rev Lett, Vol. 48(3), pp. 196-198, 1982.
- [7] S. Das Sharma and Wu-yan Lai, "Screening and elementary excitations in narrow-channel semiconductor microstructures", Phys Rev B, Vol. 32(2), pp.1401-1404, 1985.
- [8] P.J Simmonds., S.N. Holmes, H.E. Beere, L. Farrer, F. Sfigapis, D.A. Ritchie and M. Pepper, "Molecular beam epitaxy ofhighmobility In0.75Ga0.25AsIn0.75Ga0.25As for electron spin transport applications", Journal of vacuum science & technology, Vol. 27(4), pp. 2066-2078, 2009.
- [9] W.J. Skocpol, L.D. Jackel, E.L. Hu, R.E Howard and L.A. Fetter, "One-Dimensional Localization and Interaction Effects in Narrow (0.1-µm) Silicon Inversion Layers, Phys Rev Lett, Vol.49(13), pp. 951-956,1982.
- [10] M. Illing, G. Bacher, T. Kummel and A. Forchel, D. Hommel, B. Jobst and G. Landwehr, "Fabrication of CdZnSe/ZnSe quantum dots and quantum wires by electron beam lithography and wet chemical etching", Journal of vacuum science & technology B, Vol.13(6), pp. 2792-2796, 1995.
- [11] A. Sjolander and M.J. Stott, "Electron distribution around positrons in metal"s, Solid State Commun, Vol. 8(22), pp. 1881-1884,1970.
- [12] A. Sjolander and M.J. Stott., "Electron Distribution around Mobile and Fixed Point Charges in Metals", Phys Rev B, Vol. 5(6), pp. 2109-2117,1972.
- [13] S.P. Tewari, J. Sood & G. Dhingra, "Temperature dependent positron annihilation in one dimensional weakly coupled one component plasma", Indian J of Pure & Appl Phys, Vol. 45(9), pp.738-740, 2007.
- [14] S. Ichimaru, "Theory of fluctuations in a plasma", Ann Phys, Vol. 20(1), pp. 78-118, 1962.
- [15] S. Ichimaru, *"Statistical Plasma Physics"*, Addision Wesley Publishing Company, Boston, **United states**, 1992.
- [16] R.O. Dendy, "Plasma Dynamics", Oxford, Clarendon, 1990.
- [17] S.P. Tewari & J. Sood, "complex dielectric function and collective dynamics of one-dimensional weakly coupled quantum and classical hot plasmas", Indian J of Pure & Appl Phys, Vol. 42(7), pp. 518-523, 2004.
- [18] Q.P. Li and S. Das Sharma, "Elementary excitation spectrum of one-dimensional electron systems in confined semiconductor structures: Zero magnetic field", Phys Rev B, Vol. 43(14), pp.11768-11786,1991.
- [19] S.P. Tewari, H. Joshi & K. Bera, "Wave-vector and frequencydependent collective modes in one-component rare hot quantum and classical plasmas", J Phys: Cond Matter, Vol.7, pp. 8045, 1995.
- [20] B.A. Trubnikov and V.F. Elesin, "Quantum Correlation Functions in a Maxwellian Plasma", Sov Phys JETP, Vol. 20(4), pp. 866-872,1965.
- [21] G. Burns, "Solid State Physics", Academic Press, New York and London, 1985.

AUTHORS PROFILE

Dr. Grima Dhingra did M.Sc. in Physics from Department of Physics and Astrophysics, University of Delhi, with specialization in Condensed Matter Physics. She completed her Ph.D. in 2009 from University of Delhi. Her areas of research are 'Fluid Dynamics' and 'Plasma



Physics' and 'Cryptography'. She has published around twelve research papers in reputed, peer-reviewed and citation indexed international journals. She has presented many of her research papers in international and national conferences. She has been granted and successfully completed UGC minor project in 2012-14. Dr. Grima is a life member of materials research society of India (MRSI). Currently, she is working as Assistant Professor in the Department of Physics, M.D. University, Rohtak, Haryana. She has 3 years of UG and 8 years of PG teaching experience and has 11 years of research experience.

© 2019, IJSRPAS All Rights Reserved